

Triacs

Bidirectional Triode Thyristors

... designed primarily for industrial and military applications for the control of ac loads in applications such as light dimmers, power supplies, heating controls, motor controls, welding equipment and power switching systems; or wherever full-wave, silicon gate controlled solid-state devices are needed.

- All Diffused and Glass Passivated Junctions for Greater Stability
- Pressfit, Stud and Isolated Stud Packages
- Gate Triggering Guaranteed In All 3 Quadrants

SC260
SC260()3
SC261

TRIACs
25 AMPERES RMS
200 thru 600 VOLTS

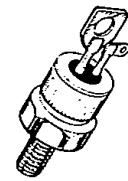


MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Repetitive Peak Off-State Voltage ($T_C = -40^\circ\text{C}$ to $+115^\circ\text{C}$) SC260B, SC260B3, SC261B SC260D, SC260D3, SC261D SC260M, SC260M3, SC261M	V _{DRM}	200 400 600	Volts
RMS On-State Current	I _{T(RMS)}	25	Amps
Peak Non-Repetitive Surge Current (One Cycle, 60 Hz)	I _{TSM}	250	Amps
Circuit Fusing Considerations t = 1 ms t = 8.3 ms	I ² t	150 260	A ² s
Peak Gate Power (Pulse Width = 10 μs)	P _{GM}	10	Watts
Average Gate Power	P _{G(AV)}	0.5	Watt
Peak Gate Power	I _{GM}	2	Amps
Operating Junction Temperature Range	T _J	-40 to +115	°C
Storage Temperature Range	T _{stg}	-40 to +125	°C
Stud Torque	—	30	in. lb.

THERMAL CHARACTERISTICS

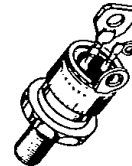
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case SC260, SC261 SC260()3	R _{θJC}	1.8 1.95	°C/W



CASE 263-04
STYLE 2
SC260



CASE 310-02
STYLE 2
SC261



CASE 311-02
STYLE 2
SC260()3

ELECTRICAL CHARACTERISTICS ($T_C = +25^\circ\text{C}$ unless otherwise noted. Values apply for either polarity of Main Terminal 2 Characteristics referenced to Main Terminal 1.)

Characteristic	Symbol	Min	Typ	Max	Unit
Peak Forward or Reverse Blocking Current (Rated V_{DRM} or V_{RRM} , gate open) $T_C = 25^\circ\text{C}$ $T_C = +115^\circ\text{C}$	I_{DRM}, I_{RRM}	— —	— —	10 1	μA mA
Peak On-State Voltage ($I_{TM} = 35 \text{ A Peak}$, Pulse Width = 1 ms, Duty Cycle $\leq 2\%$)	V_{TM}	—	—	1.58	Volts
Critical Rate of Rise of Off-State Voltage (Rated V_{DRM} , Gate Open-Circuited, Exponential Waveform) $T_C = +115^\circ\text{C}$	dv/dt	50	—	—	$\text{V}/\mu\text{s}$
Critical Rate-of-Rise of Commutating Off-State Voltage ($I_{T(RMS)} = \text{Rated RMS On-State Current}$) ($V_{DRM} = \text{Rated Peak Off-State Voltage}$, Gate Open-Circuited, Commutating $di/dt = 13.5 \text{ A/ms}$) $T_C = +80^\circ\text{C}$	$dv/dt(c)$	5	—	—	$\text{V}/\mu\text{s}$
DC Gate Trigger Current (Continuous dc) ($V_D = 12 \text{ Vdc}$) MT2(+), G(+); MT2(-), G(-); $R_L = 100 \text{ Ohms}$ MT2(+), G(-); $R_L = 50 \text{ Ohms}$	I_{GT}	— —	— —	50 50	mA_{dc}
DC Gate Trigger Current (Continuous dc) ($V_D = 12 \text{ Vdc}$) $T_C = -40^\circ\text{C}$ MT2(+), G(+); MT2(-), G(-); $R_L = 50 \text{ Ohms}$ MT2(+), G(-); $R_L = 25 \text{ Ohms}$	I_{GT}	— —	— —	80 80	mA_{dc}
DC Gate Trigger Voltage (Continuous dc) ($V_D = 12 \text{ Vdc}$) MT2(+), G(+); MT2(-), G(-); $R_L = 100 \text{ Ohms}$ MT2(+), G(-); $R_L = 50 \text{ Ohms}$	V_{GT}	— —	— —	2.5 2.5	Vdc
DC Gate Trigger Voltage (Continuous dc) ($V_D = 12 \text{ Vdc}$) $T_C = -40^\circ\text{C}$ MT2(+), G(+); MT2(-), G(-); $R_L = 50 \text{ Ohms}$ MT2(+), G(-); $R_L = 25 \text{ Ohms}$	V_{GT}	— —	— —	3.5 3.5	Vdc
DC Gate Non-Trigger Voltage ($V_D = \text{Rated } V_{DRM}$, $R_L = 1 \text{ K Ohms}$, All Trigger Modes) $T_C = 115^\circ\text{C}$	V_{GD}	0.25	—	—	Vdc
Holding Current ($V_D = 24 \text{ Vdc}$, Peak Initiating Current = 0.5 A, Pulse Width = 0.1 to 10 ms, Gate Trigger Source = 7 V, 20 Ohms) $T_C = +25^\circ\text{C}$ $T_C = -40^\circ\text{C}$	I_H	— —	— —	75 100	mA_{dc}
Latching Current ($V_D = 24 \text{ Vdc}$, Gate Trigger Source = 15 V, 100 Ohms, Pulse Width = 50 μs , 5 μs Maximum Rise and Fall Times) MT2(+), G(+); MT2(-), G(-) $T_C = 25^\circ\text{C}$ MT2(+), G(-) $T_C = 25^\circ\text{C}$ MT2(+), G(+); MT2(-), G(-) $T_C = -40^\circ\text{C}$ MT2(+), G(-) $T_C = -40^\circ\text{C}$	I_L	— — — —	— — — —	100 200 200 400	mA_{dc}

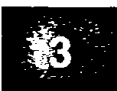


FIGURE 1 – CURRENT DERATING

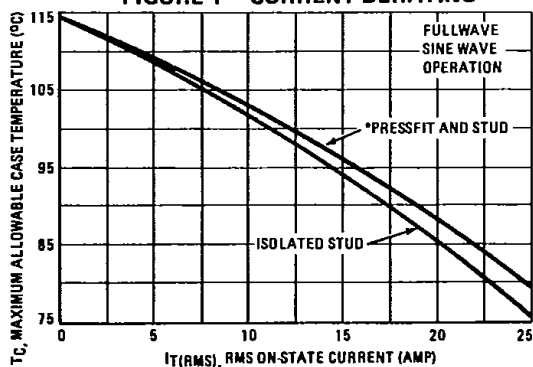
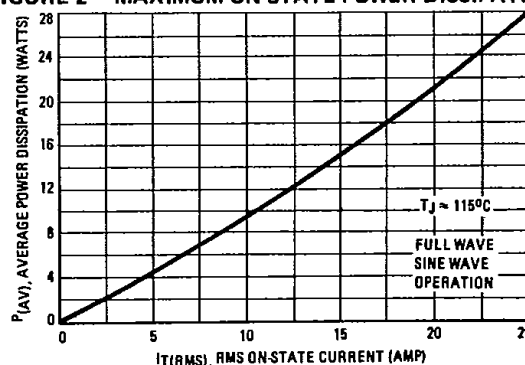


FIGURE 2 – MAXIMUM ON-STATE POWER DISSIPATION



MOTOROLA THYRISTOR DEVICE DATA

3-315